Product / Process Change Notification



N° 2017-039-A

Dear Customer.

Please find attached our INFINEON Technologies PCN:

Introduction of additional wafer production site with 12" Wafer diameter for IGBT4 1200V (T4) and IGBT HighSpeed 3 (H3) technology. Furthermore 8" wafer diameter will be introduced for Diode EC4 1200V technology

Important information for your attention:

- Please respond to this PCN by indicating your decision on the approval form, sign it and return to your sales partner before 25. May 2017.
- Infineon aligns with the widely-recognized JEDEC STANDARD "JESD46", which stipulates: "Lack of acknowledgement of the PCN within 30 days constitutes acceptance of the change."

Your prompt reply will help Infineon Technologies to assure a smooth and well executed transition. If Infineon does not hear from your side by the due date, we will assume your full acceptance to this proposed change and its implementation.

Your attention and response to this matter is greatly appreciated.

Infineon Technologies AG
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Chairman of the Supervisory Board: Wolfgang Mayrhuber
Management Board: Dr. Reinhard Ploss (CEO), Dominik Asam, Dr. Helmut Gassel, Jochen Hanebeck
Registered Office: Neubiberg Commercial Register
Amtsgericht München HRB 126492

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► Products affected: Sales Name SP N° OPN Package

1200V IGBT4 Modules

Please refer to attached affected product list 1_cip17039a

Detailed Change Information:

Subject: Introduction of additional wafer production site with

- 12" inch (300mm) wafer diameter capability for IGBT Chips and
- 8" inch (200mm) wafer diameter for Diode products.

Reason: Capacity extension and increasing security of supply 1200V IGBT4, IGBT HighSpeed 3 and Diode

<u>For IGBT products</u> 12" wafer manufacturing technology is meanwhile the established technology at IFX

<u>For Diodes</u> the 8" wafer manufacturing technology is, State of the Art' wafer manufacturing technology at Infineon. Therefore, the above mentioned products will be shifted from 6" inch wafer diameter to 8" inch wafer diameter.

Description: Old New IGBT ■ IGBT 8" inch: 8" inch: - Front end Villach/ Austria - Front end Villach, Austria - Front end Kulim/ Malaysia - Front end Kulim/ Malaysia - Front end Dresden/ Germany → Target production site front end Dresden/ Germany 12" inch Diode Diode 6" inch: 6" inch - Front end Villach/ Austria - Front end Villach/ Austria 8" inch: - Front end Villach/ Austria →Target production site front end Villach/ Austria 8" inch

► Product Identification: Individual module material number.

See attached list of affected products 1_cip17039a

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▶ Impact of Change: No impact on electrical performance. Quality and reliability verified by

qualification. There is no change in form, fit and function There is no change in the assembly process at Infineon.

► Attachment: Affected product list 1_cip17039a

► Time Schedule:

Final qualification report: On request

First samples available: On request

Intended start of delivery: 01-Sept-2017 or directly after customer approval

If you have any questions, please do not hesitate to contact your local Sales office.

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Click to view similar products for Infineon manufacturer:

Other Similar products are found below:

BSM50GB60DLC FF600R17KF6C_B2 DD260N12KHPSA1 8500808-9 DATA-94-5231 FD401R17KF6C_B2 FF401R17KF6C_B2 FF150R12MS4GBOSA1 SPW21N50C3 IRFS31N20D XMC1100T038X0064AAXUMA1 BUZ30AHXKSA1 FZ400R17KE3HOSA1 IRF2807 SPA07N60CFD SPP04N50C3XKSA1 IRL2910 IRFS52N15DHR BGA231N7E6327XTSA2 IRGP20B60PD TDA21310XUSA1 IRF7832 IRF7422D2 IRF7301 IRFR3518 TLE4296G V30 IRFZ24N IDD05SG60C IRFP260N IRF7316 IFX25001TCV10ATMA1 IRFR3704 IRLIZ44N BTT6030-2EKA BSP299 H6327 IFX2931GV33XUMA1 XMC1301T016X0016AAXUMA1 IPU60R2K0C6BKMA1 IPP80N06S4L-07 BSR302N L6327 IPU60R1K4C6 IRF7805 IRLR8103V BSL802SNH6327XTSA1 IRFR3910 IRFS59N10D IRFS59N10DTRR EVALM113023645ATOBO1 EVALM11302TOBO1 FD1000R33HE3-K